

/ Descriptions

TO-92 NPN Silicon NPN transistor in a TO-92 Plastic Package.

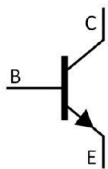
/ Features

2SA1029
Complementary pair with 2SA1029.

/ Applications

Low frequency amplifier r.

/ Equivalent Circuit



/ Pinning



PIN1 Base PIN 2 Collector PIN 3 Emitter

/ hFE Classifications & Marking

h _{FE} Classifications Symbol	B	C	D
h _{FE} Range	100~200	160~320	250~500

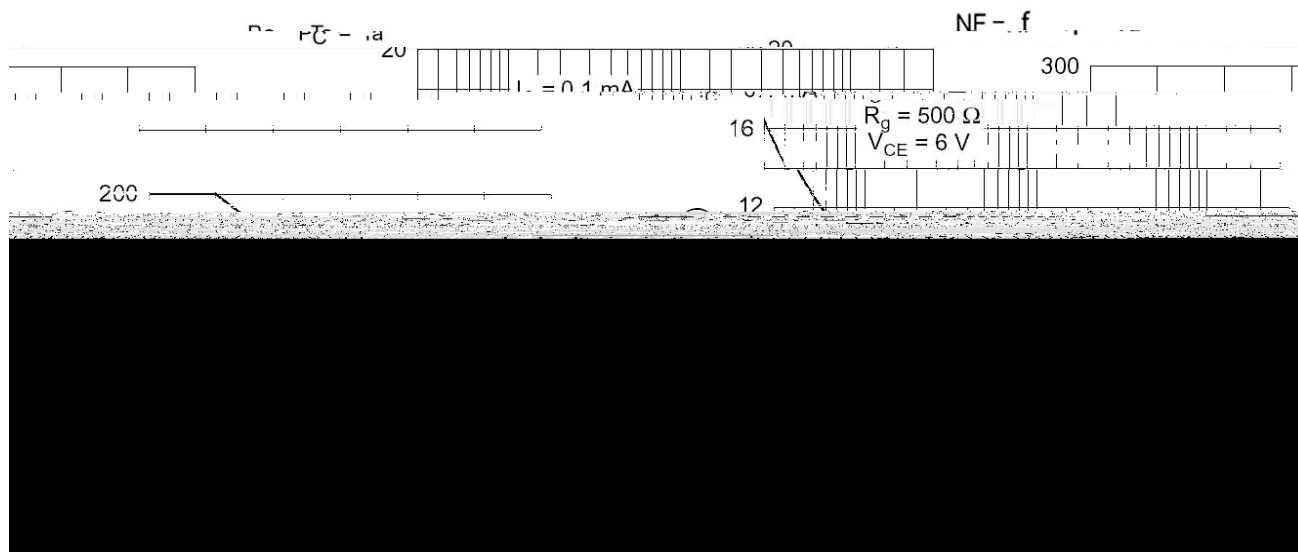
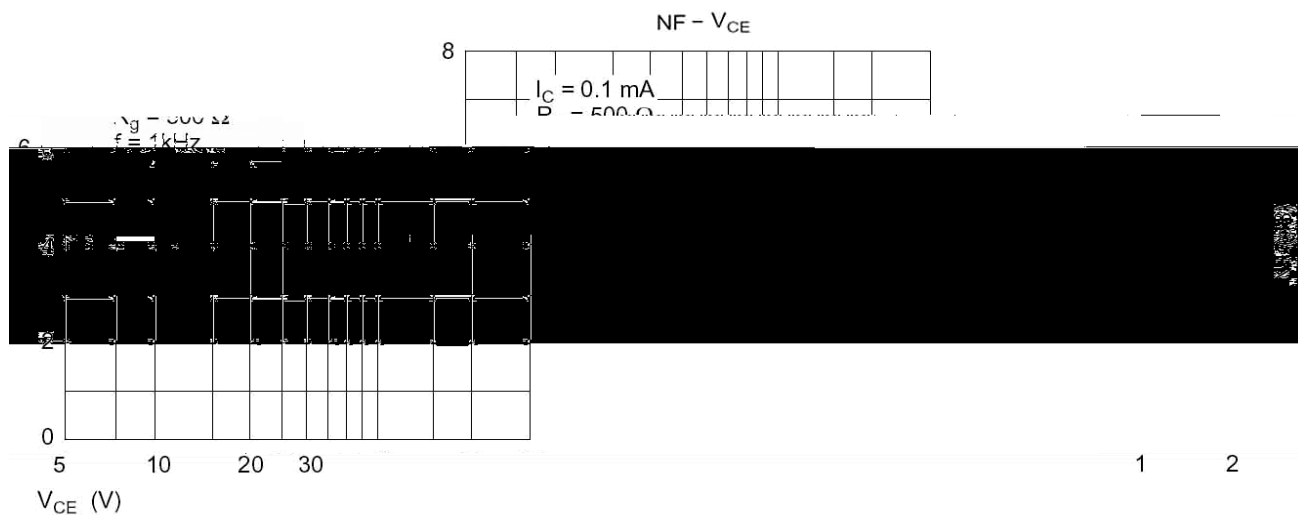
/ Absolute Maximum Ratings ($T_a=25^\circ\text{C}$)

Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	30	V
Collector to Emitter Voltage	V_{CEO}	30	V
Emitter to Base Voltage	V_{EBO}	5.0	V
Collector Current - Continuous	I_C	100	mA
Emitter Current - Continuous	I_E	-100	mA
Collector Power Dissipation	P_C	200	mW
Junction Temperature	T_j	150	
Storage Temperature Range	T_{stg}	-55 ~ 150	

/ Electrical Characteristics ($T_a=25^\circ\text{C}$)

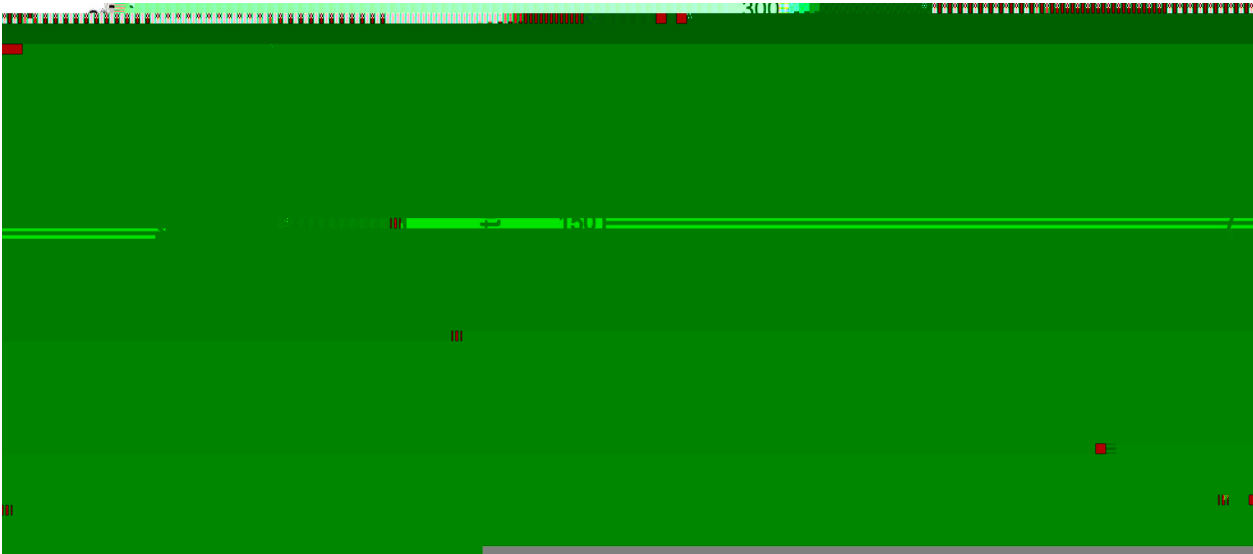
Parameter	Symbol	Test Conditions	Min	Typ		
Collector to Base Breakdown Voltage	V_{CBO}	$I_C=10\mu\text{A}$ $I_E=0$	30			V
Collector to Emitter Breakdown Voltage	V_{CEO}	$I_C=1.0\text{mA}$ $R_{BE}=\infty$	30			V
Emitter to Base Breakdown Voltage	V_{EBO}	$I_C=0$	5.0			V
Collector Cut-Off Current	I_{CBO}	$V_{CE}=18\text{V}$ $I_E=0$			0.5	μA
Emitter Cut-Off Current	I_{EBO}	$V_{BE}=2.0\text{V}$ $I_C=0$			0.5	μA
DC Current Gain	h_{FE}	$V_{CE}=12\text{V}$ $I_C=2.0\text{mA}$	100		500	
Collector to Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=10\text{mA}$ $I_B=1.0\text{mA}$			0.2	V
Base to Emitter Voltage	V_{BE}	$V_{CE}=12\text{V}$ $I_C=2.0\text{mA}$		0.67	0.75	V
Collector Output Capacitance	C_{ic}	$V_{CE}=10\text{V}$ $f=1.0\text{MHz}$ $I_E=0$				
Noise Figure	NF	$V_{CE}=6.0\text{V}$ $f=1.0\text{KHz}$ $I_C=0.1\text{mA}$ $R_{in}=500\Omega$		4.0	10	dB
Small Signal Input Impedance	h_{ie}	$V_{CE}=5.0\text{V}$ $f=270\text{Hz}$ $I_C=0.1\text{mA}$				
Small Signal Voltage Feedback Ratio	h_{re}	$V_{CE}=5.0\text{V}$ $f=270\text{Hz}$ $I_C=0.1\text{mA}$				-6
Small Signal Current Feedback Ratio	h_{fe}	$V_{CE}=5.0\text{V}$ $f=270\text{Hz}$ $I_C=0.1\text{mA}$				
Small Signal Output Admittance	h_{oe}	$V_{CE}=5.0\text{V}$ $f=270\text{Hz}$ $I_C=0.1\text{mA}$				

/ Electrical Characteristic Curve



2SC458

() / Temperature Profile for Dip Soldering(Pb-Free)



- 1

25 150

60 90sec;

2

255±5

5±0.5sec;

3

2 10 /sec.
- Note:
1.Preheating:25~150 , Time:60~90sec.
2.Peak Temp.:255±5 , Duration:5±0.5sec.
3. Cooling Speed: 2~10 /sec.

/ Resistance to Soldering Heat Test Conditions

270±5

10±1 sec.

Temp:270±5

Time:10±1 sec

/ Packaging SPEC.

/ BULK

Package Type	Units	Dimension	(unit mm3)
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